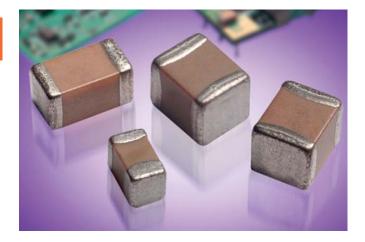
COG (NP0) Dielectric





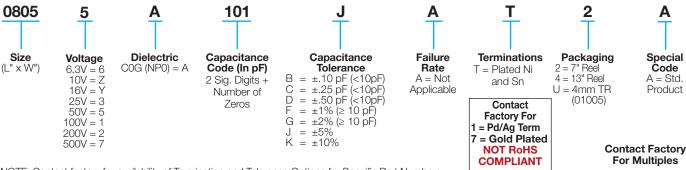


COG (NPO) is the most popular formulation of the "temperature-compensating," EIA Class I ceramic materials. Modern COG (NPO) formulations contain neodymium, samarium and other rare earth oxides.

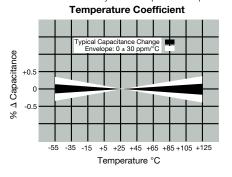
COG (NP0) ceramics offer one of the most stable capacitor dielectrics available. Capacitance change with temperature is 0 $\pm 30 \mathrm{ppm/^\circ C}$ which is less than $\pm 0.3\%$ $\Delta\mathrm{C}$ from -55°C to +125°C. Capacitance drift or hysteresis for COG (NP0) ceramics is negligible at less than $\pm 0.05\%$ versus up to $\pm 2\%$ for films. Typical capacitance change with life is less than $\pm 0.1\%$ for COG (NP0), one-fifth that shown by most other dielectrics. COG (NP0) formulations show no aging characteristics.

PART NUMBER (see page 2 for complete part number explanation)

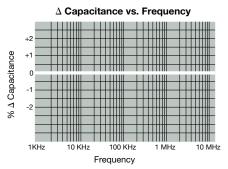




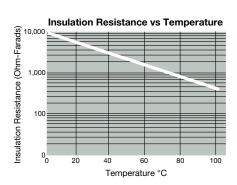
NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.



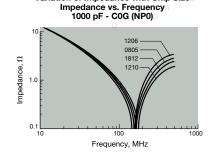
Variation of Impedance with Cap Value



Variation of Impedance with Chip Size



Impedance vs. Frequency 0805 - COG (NPO) 10 pF vs. 100 pF vs. 1000 pF vs. 1000



Impedance vs. Frequency
1000 pF - COG (NPO) vs X7R
0805

10.00

STR NPO

10.00

To 1000

Frequency, MHz

Variation of Impedance with Ceramic Formulation



C0G (NP0) Dielectric



Specifications and Test Methods

	ter/Test	NP0 Specification Limits	Measuring Conditions						
Operating Temp		-55°C to +125°C	Temperature Cycle Chamber						
Capac	itance	Within specified tolerance	Freq.: 1.0 MHz ± 10% for cap ≤ 1000 pF						
)	<30 pF: Q≥ 400+20 x Cap Value	1.0 kHz \pm 10% for cap > 1000 pF						
		≥30 pF: Q≥ 1000	Voltage: 1.0Vrms ± .2V						
Insulation	Resistance	100,000MΩ or 1000MΩ - μF,	Charge device with rated voltage for						
		whichever is less	60 ± 5 secs @ room temp/humidity Charge device with 300% of rated voltage for						
Dielectric	Strength	No breakdown or visual defects	1-5 seconds, w/charge and discharge current limited to 50 mA (max)						
			Note: Charge device with 150% of rated voltage for 500V devices.						
Resistance to Flexure Stresses	Appearance	No defects	Deflection: 2mm Test Time: 30 seconds 1mm/sec 90 mm						
	Capacitance Variation	±5% or ±.5 pF, whichever is greater							
	Q	Meets Initial Values (As Above)							
	Insulation Resistance	≥ Initial Value x 0.3							
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic solder at 230 \pm 5°C for 5.0 \pm 0.5 seconds						
Resistance to Solder Heat	Appearance	No defects, <25% leaching of either end terminal							
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± 2 hours before measuring electrical properties.						
	Q	Meets Initial Values (As Above)							
	Insulation Resistance	Meets Initial Values (As Above)							
	Dielectric Strength	Meets Initial Values (As Above)							
	Appearance	No visual defects	Step 1: -55°C ± 2° 30 ± 3 minutes						
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp ≤ 3 minutes						
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2° 30 ± 3 minutes						
Onook	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp ≤ 3 minutes						
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles and measure after 24 hours at room temperature						
	Appearance	No visual defects							
Load Life	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with twice rated voltage in						
	Q (C=Nominal Cap)	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	test chamber set at 125°C ± 2°C for 1000 hours (+48, -0). Remove from test chamber and stabilize at room temperature for 24 hours before measuring.						
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)							
	Dielectric Strength	Meets Initial Values (As Above)							
Load Humidity	Appearance	No visual defects							
	Capacitance Variation	≤ ±5.0% or ± .5 pF, whichever is greater	Store in a test chamber set at 85°C ± 2°C/85% ± 5% relative humidity for 1000 hours (+48, -0) with rated voltage applied. Remove from chamber and stabilize at room temperature for 24 ± 2 hours before measuring.						
	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C							
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)							
	Dielectric Strength	Meets Initial Values (As Above)							



COG (NP0) Dielectric





PREFERRED SIZES ARE SHADED

SIZE 0101* 0201 0402 0603 0805 1206 Soldering Reflow Only Reflow Only Reflow/Wave Reflow/Wave Reflow/Wave Reflow/Wave All Paper **Packaging** All Paper All Paper All Paper Paper/Embossed Paper/Embossed 1.60 ± 0.15 (0.063 ± 0.006) 2.01 ± 0.20 (0.079 ± 0.008) (L) Length 0.016 ± 0.0008 (0.024 ± 0.001) (0.040 ± 0.004) (0.126 ± 0.008) 0.20 ± 0.02 0.30 ± 0.03 0.81 ± 0.15 1.25 ± 0.20 (W) Width (0.008 ± 0.0008) (0.011 ± 0.001) (0.020 ± 0.004) (0.032 ± 0.006) (0.049 ± 0.008) (0.063 ± 0.008) 0.50 ± 0.25 (0.020 ± 0.010) 0.25 ± 0.15 (0.010 ± 0.006) 0.35 ± 0.15 (0.014 ± 0.006) 0.10 ± 0.04 0.15 ± 0.05 (0.006 ± 0.002) (t) Terminal (0.020 ± 0.010) (in.) (0.004 ± 0.016) 16 25 50 25 50 50 100 50 100 50 100 Cap (pF) 1.0 1.8 G G G G 2.2 В G 3.9 G G 4.7 5.6 ВВ G G G G G G G G 6.8 12 G G 15 18 В G G G G G G G G G 22 33 39 В G G G 56 G G G G G G G G 120 150 180 220 G М М G 390 470 560 Ρ 680 820 Q Q G G G 1200 1500 2200 M M 2700 3300 Ν М Q 3900 4700 5600 М 6800 М 8200 Cap 0.010 (µF) 0.012 0.015 0.018 0.022 0.027 0.039 0.068 0.082 100 200 200 500 WVDC 50 16 16 100 SIZE 0101 0402 0603 0805 0201 1206 Letter 0.56 0.90 0.94 1.27 1.40 1.78 2.29 2.54 2.79 **Thickness** (0.013)(0.009)(0.022)(0.028)(0.040)(0.050)(0.060)(0.070)(0.090)(0.100)(0.110)**PAPER EMBOSSED**

*FIA 01005



C0G (NP0) Dielectric



Capacitance Range

PREFERRED SIZES ARE SHADED

PREF	ENN	ED .	312 1	13 A	ne .	ЭПА	DEI						пп						п		
SIZ	Έ	1210 Reflow Only			1812					1825			2220				2225				
Solde	ring				Reflow Only				R	Reflow On	ly	F	Reflow Or	nly	R	eflow On	ly				
Packa		Paper/Embossed			All Embossed				All Embossed			All Embossed			All Embossed						
(L) Length	mm (in.)	3.20 ± 0.20 (0.126 ± 0.008)			4.50 ± 0.30 (0.177 ± 0.012)				4.50 ± 0.30 (0.177 ± 0.012)			5.70 ± 0.40 (0.225 ± 0.016)				5.72 ± 0.25 (0.225 ± 0.010)					
(W) Width	mm (in.)	2.50 ± 0.20 (0.098 ± 0.008)			3.20 ± 0.20 (0.126 ± 0.008)				6.40 ± 0.40 (0.252 ± 0.016)			5.00 ± 0.40 (0.197 ± 0.016)			6.35 ± 0.25 (0.250 ± 0.010)						
(t) Terminal	mm	0.50 ± 0.25			0.61 ± 0.36					0.61 ± 0.36			0.64 ± 0.39			0.64 ± 0.39					
(1)	(in.) WVDC	(0.020 ± 0.010) 25 50 100 200 500			(0.024 ± 0.014) 25 50 100 200 500			(0.024 ± 0.014) 50 100 200			(0.025 ± 0.015) 50 100 200			(0.025 ± 0.015) 50 100 200							
Сар	0.5	20	- 00	100	200	000	20	- 00	100	200	000	- 00	100	200	- 00	100	200	- 00	100	200	
(pF)	1.0 1.2																				
	1.5																				
	1.8																				
	2.2 2.7																_		$\leq W$	>	
	3.3															┌ ~	≥ ً`			ÎT	
	3.9 4.7)).		1	
	5.6															_	_				
	6.8 8.2																	_t			
	10					J										Τ					
	12 15					J															
-	18					J															
	22 27					J J															
	33					J															
	39					J															
	47 56					J															
	68					J															
	82 100					J															
	120					J															
	150 180					J		-													
	220					J															
	270 330					J															
	390					M															
	470					M															
	560 680	J J	J	J	J K	M P															
	820	J	J	J	K	Р	17	16											.,		
	1000 1200	J P	J P	P P	P P	P P	K K	K K	N N	N N	M M	M M	M M	M M				M M	M M	P P	
	1500	Р	Р	Р	Р	Р	K	K	N	N	М	М	М	М				М	М	Р	
	1800 2200	P P	P P	P P	P P		K K	K K	N N	N N	M P	M X	M X	M M				M M	M M	P P	
	2700	Р	Р	Р	P		K	K	N	Р	Q	Х	Х	М				М	М	Р	
	3300 3900	P P	P P	P P			K K	K	N N	P P	Q	X	X	X X			X	M M	M M	P P	
	4700	P	P	Р			K	K	N	Р	Q	Х	Х	Χ	Χ	Х	Х	М	М	P	
	5600 6800	P P	P P	P P			K K	K K	P X	P X	Х	X	X	X	X X	X	X	M M	M M	P P	
	8200	Р	Р				K	М				Х	Х	Χ	Х	Х	Х	М	М	Р	
Cap (µF)	0.010 0.012	P P	N N				K K	M M				X X	X	X X	X	X	X	M M	M M	P P	
(Fit)	0.015		ı V				Р	Р				X	Х	Χ	Х	Х	Х	М	М	Υ	
	0.018 0.022						P P	P P				X X	X	X	X	X	Х	M M	M Y	Y Y	
	0.027						Р	Р				Х	Х	Υ	Х	Х		Р	Υ	Υ	
	0.033 0.039						P X	P X				X X	Х		X Y	Х		X X	Y Y	Y Y	
	0.039						X	X				X			Y			X	Z		
_	0.068						Z	Z							Z			Х	Z		
	0.082 0.1						Z Z	Z Z							Z Z			X Z	Z Z		
	WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200	50	100	200	
	SIZE			1210					1812				1825			2220			2225		
Letter Max.	A 0.33	0.5		E 0.71	G 0.90	0.9		K 1.02	M 1.27	1	۱ 40	P 1.52	Q 1.78	2.5		Y 2.54	Z 2.79				
Thickness	(0.013)	(0.0)		0.71	(0.035)	(0.0)		(0.040)	(0.050)			(0.060)	(0.070)			(0.100)	(0.110)				
		PAPER										EMBO		,	, , , , , , , ,						

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1812J2K00680JCT 1812J4K00102MXT 1812J5000102JCT 1812J5000103JCT 1812J5000682JCT NIN-FB391JTRF NIN-FC2R7JTRF

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2225J2500824KXT CCR07CG103KM CGA2B2C0G1H010C CGA2B2C0G1H040C CGA2B2C0G1H050C CGA2B2C0G1H060D

CGA2B2C0G1H070D CGA2B2C0G1H151J CGA2B2C0G1H1R5C CGA2B2C0G1H2R2C CGA2B2C0G1H3R3C CGA2B2C0G1H680J

CGA4J2X7R2A104K